

General Description

The MX536A and MX636 are true RMS-to-DC converters. They feature low power and are designed to accept low-level input signals from 0 to 7VRMS for the MX536A and 0 to 200mV_{RMS} for the MX636. Both devices accept complex input waveforms containing AC and DC components. They can be operated from either a single supply or dual supplies. Both devices draw less than 1mA of quiescent supply current, making them ideal for battery-powered applications.

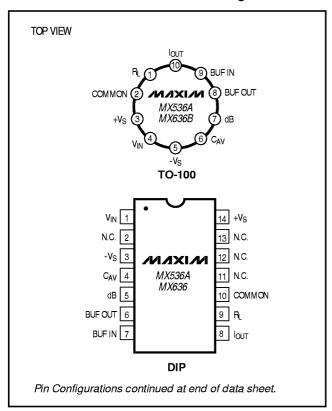
Input and output offset, positive and negative waveform symmetry (DC reversal), and full-scale accuracy are laser trimmed, so that no external trims are required to achieve full rated accuracy.

Applications

Digital Multimeters Battery-Powered Instruments Panel Meters

Process Control

Pin Configurations



Features

- **♦ True RMS-to-DC Conversion**
- ♦ Computes RMS of AC and DC Signals
- ♦ Wide Response:

2MHz Bandwidth for V_{RMS} > 1V (MX536A) 1MHz Bandwidth for V_{RMS} > 100mV (MX636)

- ♦ Auxiliary dB Output: 60dB Range (MX536A) 50dB Range (MX636)
- ♦ Single- or Dual-Supply Operation
- ♦ Low Power: 1.2mA typ (MX536A) 800μA typ (MX636)

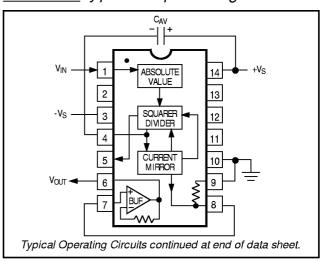
Ordering Information

PART	TEMP. RANGE	PIN-PACKAGE
MX536AJC/D	0℃ to +70℃	Dice**
MX536AJCWE	0℃ to +70℃	16 Wide SO
MX536AJD	0℃ to +70℃	14 Ceramic
MX536AJH	0℃ to +70℃	10 TO-100
MX536AJN	0℃ to +70℃	14 Plastic DIP
MX536AJQ*	0°C to +70°C	14 CERDIP
MX536AKCWE	0℃ to +70℃	16 Wide SO
MX536AKD	0℃ to +70℃	14 Ceramic
MX536AKH	0℃ to +70℃	10 TO-100
MX536AKN	0℃ to +70℃	14 Plastic DIP
MX536AKQ*	0℃ to +70℃	14 CERDIP
MX536ASD	-55℃ to +125℃	14 Ceramic

Ordering Information continued at end of data sheet.

- * Maxim reserves the right to ship ceramic packages in lieu of CERDIP packages.
- ** Dice are specified at T_A = +25 ℃.

Typical Operating Circuits



MIXIM

Maxim Integrated Products 1

ABSOLUTE MAXIMUM RATINGS

Supply Voltage: Dual Supplies (MX536A)(MX636)	
Single Supply (MX536A)	
(MX636)	+24V
Input Voltage (MX536A)	±25V
(MX636)	±12V
Power Dissipation (Package)	
Plastic DIP (derate 12mW/ °C above +75 °C)	450mW
Small Outline (derate 10mW/°C above +75°C)	400mW
Ceramic (derate 10mW/°C above +75°C)	500mW
TO-100 metal can (derate 7mW/°C above +75°C)	450mW

Output Short-Circuit Duration	Indefinite
Operating Temperature Ranges	
Commercial (J, K)	0℃ to +70℃
Military (S)	55 ℃ to +125 ℃
Storage Temperature Range	55 ℃ to +150 ℃
Lead Temperature (soldering, 10sec)	300℃

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS—MX536A

 $(T_A = +25 \,^{\circ}\text{C}, +V_S = +15 \,^{\circ}\text{V}, -V_S = -15 \,^{\circ}\text{V}, \text{ unless otherwise noted.})$

PARAMETER	CONDITIONS		MIN T	YP MAX	UNITS	
Transfer Equation			$V_{OUT} = [avg. (V_{IN})^2]^{-1/2}$			
Averaging Time Constant	Figure 3		2	25	ms/μF C _A \	
CONVERSION ACCURACY					•	
Total Error Internal Trim (Note 1)	MX536AJ, AS			±5 ±0.5	mV ±% of	
Total Error, Internal Trim (Note 1)	MX536AK			±2 ±0.2	Reading	
	T _{MIN} to +70℃	MX536AJ		±0.1 ±0.01		
Total Error va. Tamparatura		MX536AK		±0.05 ±0.005	mV ±% of	
Total Error vs. Temperature		MX536AS		±0.1 ±0.005	Reading/℃	
	+70 °C to +125 °C	MX536AS		±0.03 ±0.005	1	
Total Error vs. Supply			±0.1 ±0.01		mV ±% of Reading/\	
Tatal Forest DO Description	MX536AJ, AS MX536AK		±0.2		% of	
Total Error vs. DC Reversal			±	±0.1		
Total Error, External Trim	MX536AJ, AS		±3 ±0.3		mV ±% of	
(Note 1)	MX536AK		±2	±0.1	Reading	
ERROR vs. CREST FACTOR (No	te 2)					
	Crest Factor 1 to 2		Specified Accuracy		% of Reading	
Additional Error	Crest Factor = 3		-0.1			
	Crest Factor = 7		-1.0			
FREQUENCY RESPONSE (Note 3	3)	-			•	
	V _{IN} = 10mV		5		kHz	
Bandwidth for 1% Additional Error (0.09dB)	V _{IN} = 100mV		45			
Additional Error (0.090B)	V _{IN} = 1V		120			
	V _{IN} = 10mV		9	90	- kHz	
±3dB Bandwidth	$V_{IN} = 100 \text{mV}$		4	450		
	V _{IN} = 1V		2	2.3	MHz	

ELECTRICAL CHARACTERISTICS—MX536A (continued)

 $(T_A = +25$ °C, $+V_S = +15$ V, $-V_S = -15$ V, unless otherwise noted.)

±15V Supplies Continuous RMS Peak Tr. ±5V Supplies Continuous RMS Peak Tr. All Supplies MX536AJ, AS MX536AK TA = +25°C		13.33	0 to 7 0 to 2 16.7 0.8 0.5	±20 ±7 ±25 20.00 ±2	VRMS VPK VRMS VPK VPK VPK	
Continuous RMS Peak Tr. ±5V Supplies Continuous RMS Peak Tr. All Supplies MX536AJ, AS MX536AK	ansient	13.33	0 to 2 16.7 0.8	±7 ±25 20.00	VPK VRMS VPK VPK	
±5V Supplies Continuous RMS Peak Tr. All Supplies MX536AJ, AS MX536AK	ansient	13.33	16.7 0.8	±7 ±25 20.00	V _{RMS} V _{PK} V _{PK}	
Continuous RMS Peak Tr. All Supplies MX536AJ, AS MX536AK		13.33	16.7	±25 20.00	V _{PK}	
MX536AJ, AS MX536AK		13.33	0.8	±25 20.00	VPK	
MX536AJ, AS MX536AK	MX536AJ	13.33	0.8	20.00		
MX536AK	MX536AJ	13.33	0.8		kΩ	
MX536AK	MX536AJ			±2		
	MX536AJ		0.5		m\/	
T _A = +25°C	MX536AJ			±1	— mV	
T _A = +25°C	MX536AJ					
T _A = +25℃			±1	±2		
	MX536AK		±0.5	±1	mV	
	MX536AS			±2	\neg	
TA = TMIN to TMAX	MX536AJ, AK		±0.1		7400	
	MX536AS			±0.2	— mV/℃	
	MX536AJ, AK		±0.1		1,101	
Supply Voltage MX536AS			±0.2		mV/V	
±15V Supplies		0 to 11	12.5		1,,	
±5V Supplies		0 to 2			v	
		5			mA	
Sink		-130			μА	
			20		mA	
				0.5	Ω	
	MX536AJ		±0.4	±0.6		
	MX536AK		±0.2	±0.3	dB	
OdB = TVRMS	MX536AS		±0.5	±0.6		
			-3		mV/dB	
			0.33		% of Reading/℃	
0dB = 1V _{RMS}		5	20	80	μА	
		1		100	μА	
			40		μ A /V _{RMS}	
			±10	±20	%	
		20	25	30	kΩ	
		(-V _S to (+V _S - 2.5)	V	
	TA = T _{MIN} to T _{MAX} Supply Voltage ±15V Supplies ±5V Supplies Source Sink V _{IN} = 7mV to 7V _{RMS} , 0dB = 1V _{RMS}	MX536AS TA = T _{MIN} to T _{MAX} MX536AJ, AK MX536AS MX536AJ, AK MX536AS ** ** ** ** ** ** ** ** **	MX536AS TA = TMIN to TMAX MX536AS Supply Voltage MX536AS MX536AS MX536AS MX536AS MX536AS D to 11 ±5V Supplies O to 2 Source Sink VIN = 7mV to 7VRMS, OdB = 1VRMS OdB = 1VRMS MX536AS MX536AS MX536AS MX536AS MX536AS MX536AS DOBB = 1VRMS MX536AS To 20	MX536AS TA = TMIN to TMAX MX536AS Supply Voltage MX536AS, AK MX536AS MX536AS, AK MX536AS, AK MX536AS, AK MX536AS, AK MX536AS, AK MX536AS, AK MX536AS, AR MX536AS,	MX536AS ±2 TA = TMIN to TMAX MX536AS ±0.1 MX536AS ±0.2 Supply Voltage MX536AS ±0.2 ±15V Supplies 0 to 11 12.5 ±5V Supplies 0 to 2 Source 5 Sink -130 VIN = 7mV to 7VRMS, OdB = 1VRMS MX536AS ±0.2 ±0.3 MX536AS ±0.4 ±0.6 MX536AS ±0.5 ±0.6 MX536AS ±0.5 ±0.6 MX536AS ±0.5 ±0.6 -3 0.33 0dB = 1VRMS 5 20 80 1 100	

ELECTRICAL CHARACTERISTICS—MX536A (continued)

 $(T_A = +25 \,^{\circ}\text{C}, +V_S = +15 \text{V}, -V_S = -15 \text{V}, \text{ unless otherwise noted.})$

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
BUFFER AMPLIFIER					· ·
Input and Output Voltage Range		-V _S to (+V _S - 2.5)			V
Input Offset Voltage	$R_S = 25k\Omega$		±0.5	±4	mV
Input Bias Current			20	300	nA
Input Resistance			10 ⁸		Ω
Output Compant	Source	+5			mA
Output Current	Sink	-130			μΑ
Short-Circuit Current			20		mA
Small-Signal Bandwidth			1		MHz
Slew Rate (Note 4)			5		V/µs

ELECTRICAL CHARACTERISTICS—MX636

 $(T_A = +25 \,^{\circ}\text{C}, +V_S = +3\text{V}, -V_S = -5\text{V}, \text{ unless otherwise noted.})$

PARAMETER	CONDI	CONDITIONS		UNITS
Transfer Equation				
Averaging Time Constant	Figure 3		25	ms/μF C _{AV}
CONVERSION ACCURACY				- '
Total Error, Internal Trim	MX636J		±0.5 ±1.0	mV ±% of
(Notes 5, 6)	MX636K		±0.2 ±0.5	Reading
Total Error vs. Temperature	MX636J		±0.1 ±0.01	mV ±% of
(0℃ to +70℃)	MX636K		±0.1 ±0.00	5 Reading/℃
Total Error vs. Supply				mV ±% of Reading/V
Total Error vs. DC Reversal	\/ 000m\/	MX636J	±0.2	±% of
Total Error vs. DC Reversal	V _{IN} = 200mV	MX636K	±0.1	Reading
Total Error, External Trim	MX636J	-	±0.3 ±0.1	mV ±% of
(Note 5)	MX636K		±0.1 ±0.1	Reading
ERROR vs. CREST FACTOR (Note 3)			•
	Crest Factor 1 to 2		Specified Accuracy	. 0/ 6
Additional Error	Crest Factor = 3		-0.2	±% of Reading
	Crest Factor = 6		-0.5	ricading
FREQUENCY RESPONSE (Not	es 6, 8)			
D 1 111 6 40/	V _{IN} = 10mV		14	
Bandwidth for 1% Additional Error (0.09dB)	V _{IN} = 100mV		90	kHz
raditional Error (c.coab)	V _{IN} = 200mV		130	
	V _{IN} = 10mV		100	kHz
±3dB Bandwidth	V _{IN} = 100mV		900	NΠZ
	V _{IN} = 200mV		1.5	MHz

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ELECTRICAL CHARACTERISTICS—MX636 (continued) ($T_A = +25$ °C, $+V_S = +3V$, $-V_S = -5V$, unless otherwise noted.)

PARAMETER	CONDIT	IONS	MIN	TYP	MAX	UNITS	
INPUT CHARACTERISTICS	'					-	
	Continuous RMS, All Su	pplies		0 to 200		mV _{RMS}	
land Cinnal Donne		+3V, -5V Supplies			±2.8		
Input Signal Range	Peak Transient	±2.5V Supplies			±2	V _{PK}	
		±5V Supplies			±5		
Safe Input	All Supplies				±12	V _{PK}	
Input Resistance			5.33	6.7	8.00	kΩ	
1 10" 111"	MX636J				±0.5	\/	
Input Offset Voltage	MX636K				±0.2	mV	
OUTPUT CHARACTERISTICS (No	ote 5)					-	
0" 1111	<u> </u>	MX636J			±0.5		
	T _A = +25°C	MX636K			±0.2	mV	
Offset Voltage	$T_A = T_{MIN}$ to T_{MAX}			±10		μV/°C	
	With Supply Voltage			±0.1		mV/V	
Output Voltage Swing	+3V, -5V Supplies		0 to 1			V	
Output Voltage Swing	±5V to ±16.5V Supplies	1	0 to 1	1.4			
Output Resistance			8	10	12	kΩ	
dB OUTPUT	<u>'</u>						
Error	7 1/ (1/ (000)/	MX636J		±0.3	±0.5	-10	
	$7\text{mV} \le V_{IN} \le 300\text{mV}$	MX636K		±0.1	±0.2	– dB	
Scale Factor				-3		mV/dB	
				+0.33		%/℃	
Scale Factor Tempco				-0.033		dB/℃	
IREF	0dB = 1V _{RMS}		2	4	8	μА	
I _{REF} Range			1		50	μA	
IOUT TERMINAL							
IOUT Scale Factor				100		μΑ/V _{RMS}	
IOUT Scale Factor Tolerance			-20	±10	+20	%	
Output Resistance			8	10	12	kΩ	
·				-V _S to			
Voltage Compliance				(+V _S - 2.0))	\ \ \ \	
BUFFER AMPLIFIER				, - ,	<u>'</u>		
			-V _S to				
Input and Output Voltage Range		(+V _S - 2)				V	
		MX636J	, ,	±0.8	±2		
Input Offset Voltage	$R_S = 10k\Omega$	MX636K		±0.5	 ±1	mV	
Input Current		Windows		100	300	nA	
Input Resistance				108		Ω	
•	Source		+5			mA	
Output Current	Sink	+	-130			μА	
Short-Circuit Current	OHK		-130	20		mA	
Small-Signal Bandwidth				1		MHz	
Slew Rate (Note 9)							
Siew hate (Note 9)				5		V/µs	

ELECTRICAL CHARACTERISTICS—MX636 (continued)

 $(T_A = +25 \,^{\circ}\text{C}, +V_S = +3\text{V}, -\text{V}_S = -5\text{V}, \text{ unless otherwise noted.})$

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
POWER SUPPLY					
Rated Performance			+3/-5		V
Dual Supplies		+2/-2.5		±16.5	V
Single Supply		+5		+24	V
Quiescent Current (Note 10)			0.8	1	mA

Note 1: Accuracy is specified for 0 to 7VRMS, DC or 1kHz sine-wave input with the MX536A connected as in Figure 2.

Note 2: Error vs. crest factor is specified as an additional error for 1V_{RMS} rectangular pulse stream, pulse width = 200µs.

Note 3: Input voltages are expressed in volts RMS, and error as % of reading.

Note 4: With $2k\Omega$ external pull-down resistor.

Note 5: Accuracy is specified for 0 to 200mV, DC or 1kHz sine-wave input. Accuracy is degraded at higher RMS signal levels.

Note 6: Measured at pin 8 of DIP and SO (IOUT), with pin 9 tied to COMMON.

Note 7: Error vs. crest factor is specified as an additional error for 200mV_{RMS} rectangular pulse input, pulse width = 200µs.

Note 8: Input voltages are expressed in volts RMS.

Note 9: With $10k\Omega$ external pull-down resistor from pin 6 (BUF OUT) to -Vs.

Note 10: With BUF input tied to COMMON.

Detailed Description

The MX536A/MX636 uses an implicit method of RMS computation that overcomes the dynamic range as well as other limitations inherent in a straightforward computation of the RMS. The actual computation performed by the MX536A/MX636 follows the equation:

The input voltage, V_{IN} , applied to the MX536A/MX636 is processed by an absolute-value/voltage to current converter that produces a unipolar current I_1 (Figure 1). This current drives one input of a squarer/divider that produces a current I_4 that has a transfer function:

$$I_4 = \frac{I_1^2}{I_3}$$

The current I₄ drives the internal current mirror through a lowpass filter formed by R1 and an external capacitor, C_{AV}. As long as the time constant of this filter is greater than the longest period of the input signal, I₄ is averaged. The current mirror returns a current, I₃, to the square/divider to complete the circuit. The current I₄ is then a function of the average of (I₁2/I₄), which is equal to I₁BMS.

The current mirror also produces a $2 \cdot 14$ output current, 1_{OUT} , that can be used directly or converted to a voltage using resistor R2 and the internal buffer to provide a low-impedance voltage output. The transfer function for the MX536A/MX636 is:

The dB output is obtained by the voltage at the emitter of Q3, which is proportional to the -log V_{IN}. The emitter follower Q5 buffers and level shifts this voltage so that the dB output is zero when the externally set emitter current for Q5 approximates I₃.

Standard Connection (Figure 2)

The standard RMS connection requires only one external component, CAV. In this configuration the MX536A/MX636 measures the RMS of the AC and DC levels present at the input, but shows an error for low-frequency inputs as a function of the CAV filter capacitor. Figure 3 gives practical values of CAV for various values of averaging error over frequency for the standard RMS connections (no post filtering). If a $3\mu F$ capacitor is chosen, the additional error at 100Hz will be 1%. If the DC error can be rejected, a capacitor should be connected in series with the input, as would typically be the case in single-supply operation.

The input and output signal ranges are a function of the supply voltages. Refer to the electrical characteristics for guaranteed performance. The buffer amplifier can be used either for lowering the output impedance of the circuit, or for other applications such as buffering high-impedance input signals. The MX536A/MX636 can be used in current output mode by disconnecting the internal load resistor, R_L , from ground. The current output is available at pin 8 (pin 10 on the "H" package) with a nominal scale of $40\mu A/V_{RMS}$ input for the MX536A and $100\mu A/V_{RMS}$ input for the MX636. The output is positive.

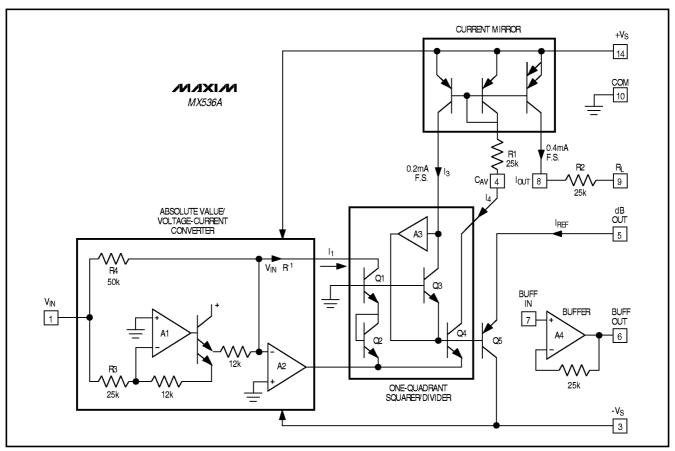


Figure 1. MX536A Simplified Schematic

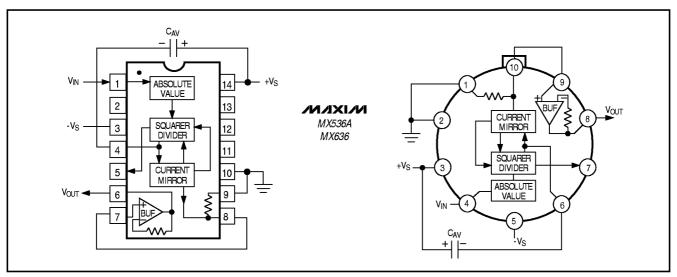


Figure 2. MX536A/MX636 Standard RMS Connection

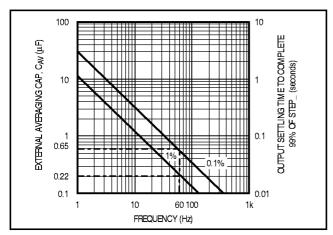


Figure 3. Lower Frequency for Stated % of Reading Error and Settling Time for Circuit shown in Figure 2

High-Accuracy Adjustments
The accuracy of the MX536A/MX636 can be improved by the addition of external trims as shown in Figure 4. R4 trims the offset. The input should be grounded and R4 adjusted to give zero volts output from pin 6. R1 is trimmed to give the correct value for either a calibrated DC input or a calibrated AC signal. For example: 200mV DC input should give 200mV DC output; a ±200mV peak-to-peak sine-wave should give 141mV DC output.

Single-Supply Operation Both the MX536A and the MX636 can be used with a single supply down to +5V (Figure 5). The major limitation of this connection is that only AC signals can be measured, since the differential input stage must be biased off ground for proper operation. The load resistor is necessary to provide output sink current. The input signal is coupled through C2 and the value chosen so that the desired low-frequency break point is obtained with the input resistance of 16.7k Ω for the MX536A and 6.7k Ω for the MX636.

Figure 5 shows how to bias pin 10 within the range of the supply voltage (pin 2 on "H" packages). It is critical that no extraneous signals are coupled into this pin. A capacitor connected between pin 10 and ground is recommended. The common pin requires less than $5\mu A$ of input current, and if the current flowing through resistors R1 and R2 is chosen to be approximately 10 times the common pin current, or $50\mu A$, the resistor values can easily be calculated.

Choosing the Averaging Time Constant Both the MX536A and MX636 compute the RMS value of AC and DC signals. At low frequencies and DC, the output tracks the input exactly; at higher frequencies,

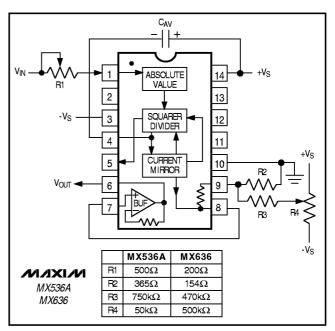


Figure 4. Optional External Gain and Output Offset Trims

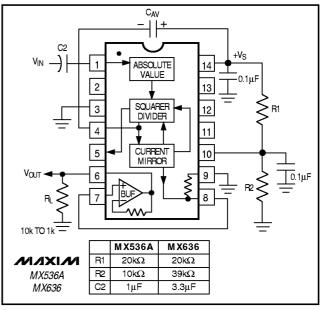


Figure 5. Single-Supply Operation

the average output approaches the RMS value of the input signal. The actual output differs from the ideal by an average (or DC) error plus some amount of ripple.

The DC error term is a function of the value of CAV and the input signal frequency. The output ripple is inverse-

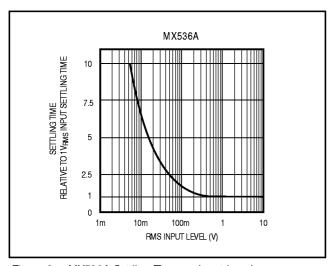


Figure 6a. MX536A Settling Time vs. Input Level

ly proportional to the value of CAV. Waveforms with high crest factors, such as a pulse train with low duty cycle, should have an average time constant chosen to be at least ten times the signal period.

Using a large value of C_{AV} to remove the output ripple increases the settling time for a step change in the input signal level. Figure 3 shows the relationship between C_{AV} and settling time, where 115ms settling equals $1\mu F$ of C_{AV} . The settling time, or time for the RMS converter to settle to within a given percent of the change in RMS level, is set by the averaging time constant, which varies approximately 2:1 between increasing and decreasing input signals. For example, increasing input signals require 2.3 time constants to settle to within 1%, and 4.6 time constants for decreasing signals levels.

In addition, the settling time also varies with input signal levels, increasing as the input signal is reduced, and decreasing as the input is increased as shown in Figures 6a and 6b.

Using Post Filters

A post filter allows a smaller value of CAV, and reduces ripple and improves the overall settling time. The value of CAV should be just large enough to give the maximum DC error at the lowest frequency of interest. The post filter is used to remove excess output ripple. Figures 7, 8, and 9 give recommended filter connections and values for both the MX536A and MX636. Table 1 lists the number of time constants required for the RMS section to settle to within different percentages of the final value for a step change in the input signal.

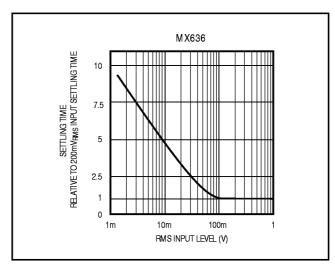


Figure 6b. MX636 Settling Time vs. Input Level

Table 1. Number of RC Time Constants (τ) Required for MX536A/MX636 RMS Converters to Settle to Within Stated % of Final Value

PARAMET	ΓERS	FOR INCREASING AMPLITUDES	FOR DECREASING AMPLITUDES
Basic Formulas	S	$\Delta V \sqrt{1 - e^{-T/RC}}$	ΔV √ e ^{-T/RC}
Settling Time to Within	1%	4.6τ/2.0τ	4.6τ/4.6τ
Stated % of New RMS	0.1%	6.9τ/3.1τ	6.9τ/6.9τ
Level	0.01%	9.2τ/4.2τ	9.2τ/9.2τ

Note: (τ) Settling Times for Linear RC Filter

Decibel Output (dB)

The dB output of the MX536A/MX636 originates in the squarer/divider section and works well over a 60dB range. The connection for dB measurements is shown in Figure 10. The dB output has a temperature drift of 0.03dB/℃, and in some applications may need to be compensated. Figure 10 shows a compensation scheme. The amplifier can be used to scale the output for a particular application. The values used in Figure 10 give an output of +100mV/dB.

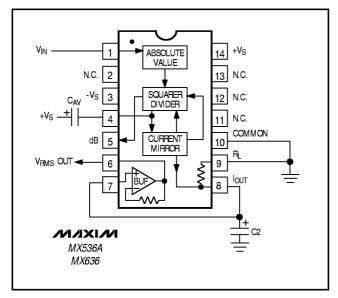


Figure 7. MX536A/MX636 with a One-Pole Output Filter

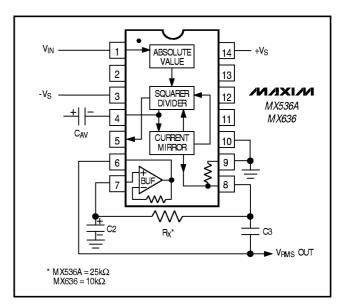


Figure 8. MX536A/MX636 with a Two-Pole Output Filter

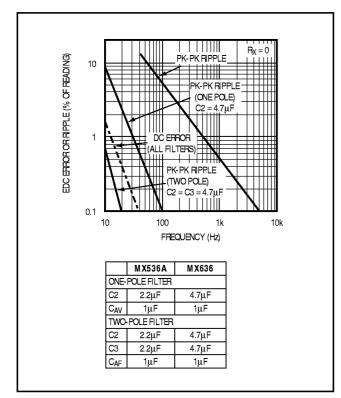


Figure 9. Performance Features of Various Filter Types for MX536A/MX636

Frequency Response

The MX536A/MX636 utilizes a logarithmic circuit in performing the RMS computation of the input signal. The bandwidth of the RMS converters is proportional to signal level. Figures 11 and 12 represent the frequency response of the converters from 10mV to 7VRMS for the MX536A and 1mV to 1V for the MX636, respectively. The dashed lines indicate the upper frequency limits for 1%, 10%, and ± 3 dB of reading additional error. Caution must be used when designing RMS measuring systems so that overload does not occur. The input clipping level for the MX636 is ± 12 V, and for the MX536A it is ± 20 V. A 7VRMS signal with a crest factor of 3 has a peak input of 21V.

Application in a Low-Cost DVM A low-cost digital voltmeter (DVM) using just two integrated circuits plus supporting circuitry and LCD display is shown in Figure 13. The MAX130 is a 3 1/2 digit integrating A/D converter with precision bandgap reference. The $10 \mathrm{M}\Omega$ input attenuator is AC coupled to pin 6 of the MX636 buffer amplifier. The output from the MX636 is connected to the MAX130 to give a direct reading to the LCD display.

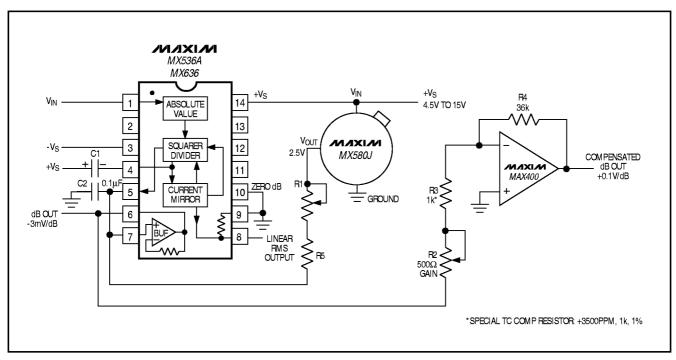


Figure 10. dB Connection

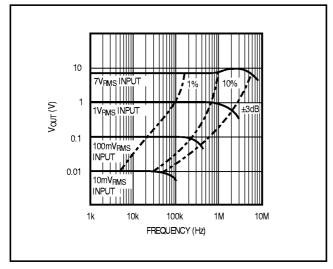


Figure 11. MX536A High-Frequency Response

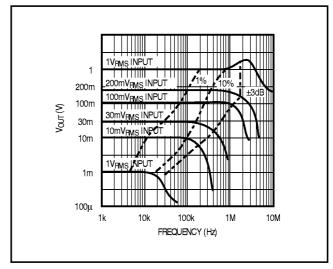


Figure 12. MX636 High-Frequency Response

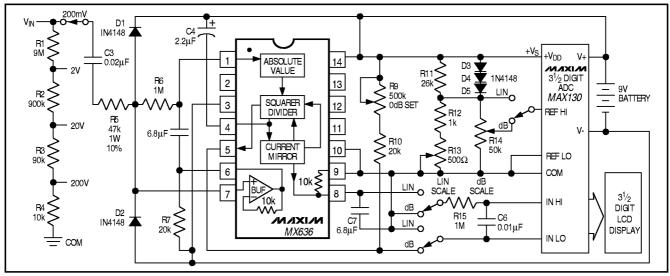
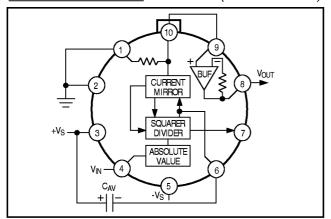
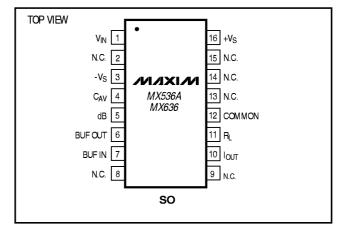


Figure 13. Portable High-Z Input RMS DPM and dB Meter

Typical Operating Circuits (continued)



__Pin Configurations (continued)



Ordering Information (continued)

PART	TEMP. RANGE	PIN-PACKAGE
MX536ASH	-55℃ to +125℃	10 TO-100
MX536ASQ*	-55℃ to +125℃	14 CERDIP
MX636JC/D	0℃ to +70℃	Dice**
MX636JCWE	0℃ to +70℃	16 Wide SO
MX636JD	0℃ to +70℃	14 Ceramic
MX636JH	0℃ to +70℃	10 TO-100
MX636JN	0°C to +70°C	14 Plastic DIP

TEMP. RANGE	PIN-PACKAGE
0℃ to +70℃	14 CERDIP
0℃ to +70℃	16 Wide SO
0℃ to +70℃	14 Ceramic
0℃ to +70℃	10 TO-100
0℃ to +70℃	14 Plastic DIP
0℃ to +70℃	14 CERDIP
	0°C to +70°C 0°C to +70°C 0°C to +70°C 0°C to +70°C 0°C to +70°C

^{*} Maxim reserves the right to ship ceramic packages in lieu of CERDIP packages.

Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.

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^{**} Dice are specified at T_A = +25 ℃.